

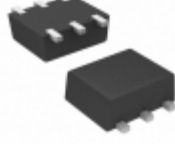
	<h2>SI1072X-T1-E3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI1072X-T1-E3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 1.3A SOT563F</p> <p><b>Datenblätter:</b>  <a href="#">SI1072X-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 33490 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI1072X-T1-E3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET N-CH 30V 1.3A SOT563F
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	33490 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Verlustleistung (max)	236mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	-
Rds On (Max) @ Id, Vgs	93 mOhm @ 1.3A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.3nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	280pF @ 15V
Verpackung	Tape & Reel (TR)


















SI1072X-T1-E3 ist neu im Original, Suche SI1072X-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1072X-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen.  
Anfrage SI1072X-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI1073X-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 0.98A SC89-6</p>	 <p><b>SI1073X-T1-E3</b> Vishay / Siliconix MOSFET P-CH 30V 0.98A SC89-6</p>	 <p><b>SI1072X-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 1.3A SOT563F</p>	 <p><b>SI1072X-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V SC89</p>
 <p><b>SI1073X-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 0.98A SC89-6</p>	 <p><b>SI1071X-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 30V 0.96A SC89-6</p>	 <p><b>SI1071X-T1-E3</b> Vishay / Siliconix MOSFET P-CH 30V 0.96A SOT563F</p>	 <p><b>SI1072X-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 30V SC89</p>

### heiße Teile

Mehr

 SI1056X-T1-E3	 SI1056X-T1-E3	 SI1056X-T1-GE3	 SI1056X-T1-GE3	 SI1058X-T1-GE3
 SI1058X-T1-GE3	 SI1065X-T1-E3	 SI1065X-T1-E3	 SI1065X-T1-GE3	 SI1065X-T1-GE3
 SI1067X-T1-E3	 SI1067X-T1-E3	 SI1067X-T1-GE3	 SI1067X-T1-GE3	 SI1069X-T1-E3
 SI1069X-T1-E3	 SI1069X-T1-GE3	 SI1069X-T1-GE3	 SI1070X-T1-E3	 SI1070X-T1-E3
 SI1070X-T1-GE3	 SI1070X-T1-GE3	 SI1071X-T1-GE3	 SI1071X-T1-GE3	 SI1072X-T1-E3
 SI1072X-T1-GE3	 SI1072X-T1-GE3	 SI1073X-T1-GE3	 SI1073X-T1-GE3	 SI1120-A-GMR
 SI1132-A10-GMR	 SI1133-AA00-GMR	 SI113DP-T1-GE3	 SI1141-A10-GMR	 SI1142-A11-GMR
 SI1143-A11-GMR	 SI1143-M01-GMR	 SI1144-AAGX-GMR	 SI1300BDL-T1-E3	 SI1300BDL-T1-E3
 SI1300BDL-T1-GE3	 SI1300BDL-T1-GE3	 SI1300DL	 SI1300DL-T1	 SI1300DL-T1-GE3
 SI1301DL	 SI1301DL-T1	 SI1301DL-T1-E3	 SI1301DL-T1-GE3	 SI1301DL-T1/LGW

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited